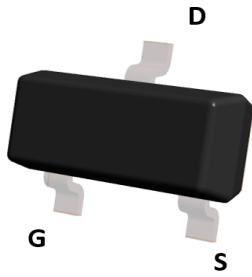
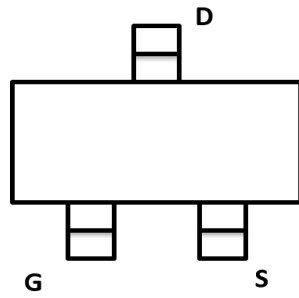


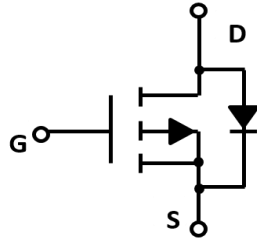
P-Channel Enhancement Mode Field Effect Transistor



Top View



SOT-23-3L



Product Summary

- V_{DS} -30V
- I_D -7.0A
- $R_{DS(ON)}$ (at $V_{GS}=-10V$) <25 mohm
- $R_{DS(ON)}$ (at $V_{GS}=-4.5V$) <36 mohm

General Description

- Trench Power LV MOSFET technology
- High density cell design for Low $R_{DS(ON)}$
- High Speed switching

Applications

- Battery protection
- Load switch
- Power management

■ Absolute Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Maximum	Unit
Drain-source Voltage	V_{DS}	-30	V
Gate-source Voltage	V_{GS}	± 20	V
Drain Current	I_D	$T_A=25^\circ\text{C}$ @ Steady State	-7.0
		$T_A=70^\circ\text{C}$ @ Steady State	-5.6
Pulsed Drain Current ^A	I_{DM}	-50	A
Total Power Dissipation @ $T_A=25^\circ\text{C}$	P_D	1.9	W
Thermal Resistance Junction-to-Ambient @ Steady State ^B	$R_{\theta JA}$	65.7	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature Range	T_J, T_{STG}	-55~+150	$^\circ\text{C}$

■ Ordering Information (Example)

PREFERRED P/N	PACKING CODE	Marking	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
YJL07P03AL	F1	3007.	3000	30000	120000	7" reel



YJL07P03AL

■ Electrical Characteristics (T_J=25°C unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Static Parameter						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250μA	-30			V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-30V, V _{GS} =0V, T _C =25°C			-1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} = ±20V, V _{DS} =0V			±100	nA
Gate Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D =-250μA	-1.0	-1.5	-2.5	V
Static Drain-Source On-Resistance	R _{DS(ON)}	V _{GS} = -10V, I _D =-7.0A		18.5	25	mΩ
		V _{GS} = -4.5V, I _D =-5.0A		24.5	36	
Diode Forward Voltage	V _{SD}	I _S =-7.0A, V _{GS} =0V		-0.8	-1.2	V
Maximum Body-Diode Continuous Current	I _S				-7.0	A
Dynamic Parameters						
Input Capacitance	C _{iss}	V _{DS} =-15V, V _{GS} =0V, f=1MHZ		1500		pF
Output Capacitance	C _{oss}			327		
Reverse Transfer Capacitance	C _{rss}			276		
Switching Parameters						
Total Gate Charge	Q _g	V _{GS} =-10V, V _{DS} =-15V, I _D =-7.0A		30		nC
Gate Source Charge	Q _{gs}			5.3		
Gate Drain Charge	Q _{gd}			7.6		
Turn-on Delay Time	t _{D(on)}	V _{GS} =-10V, V _{DS} =-15V, I _D =-4.2A, R _{GEN} =2.5Ω		14		ns
Turn-on Rise Time	t _r			20		
Turn-off Delay Time	t _{D(off)}			95		
Turn-off Fall Time	t _f			65		

A. Repetitive Rating: Pulse width limited by maximum junction temperature.

B. Surface Mounted on FR4 Board, t ≤ 10 sec.



■ Typical Performance Characteristics

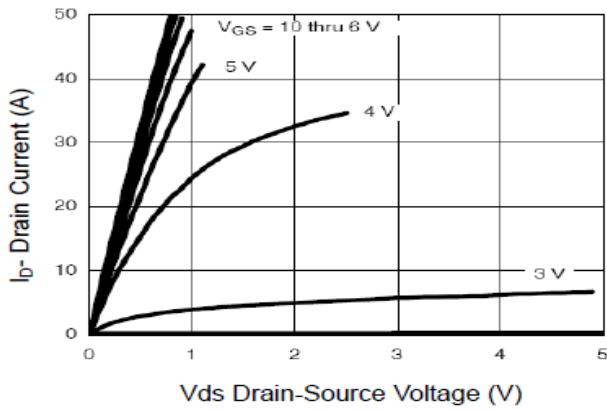


Figure1. Output Characteristics

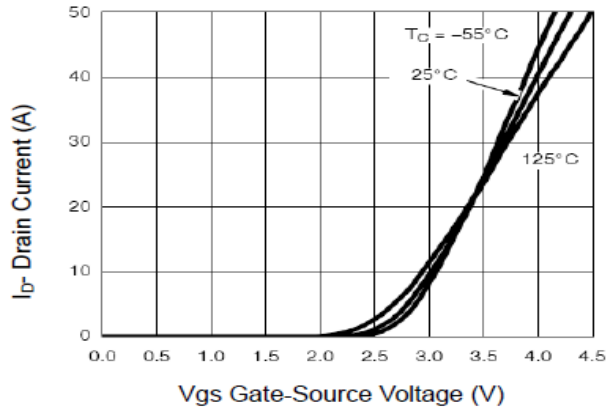


Figure2. Transfer Characteristics

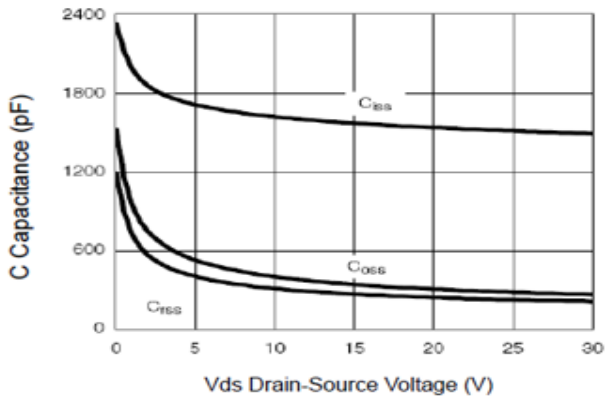


Figure3. Capacitance Characteristics

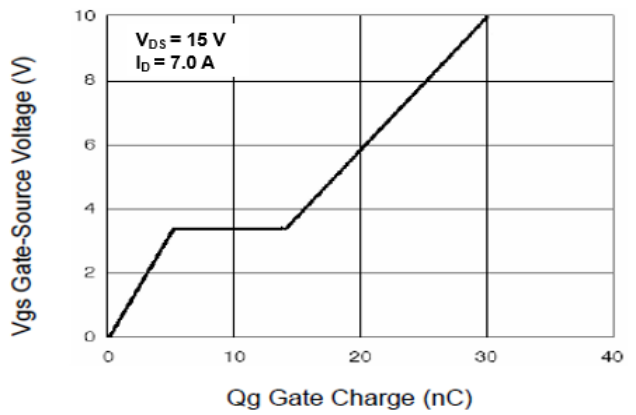


Figure4. Gate Charge

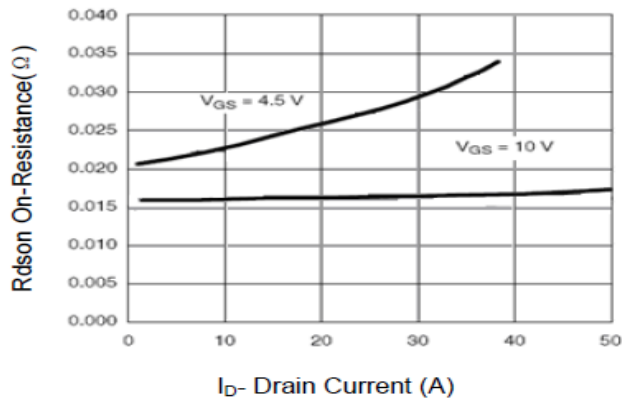


Figure5. Drain-Source on Resistance

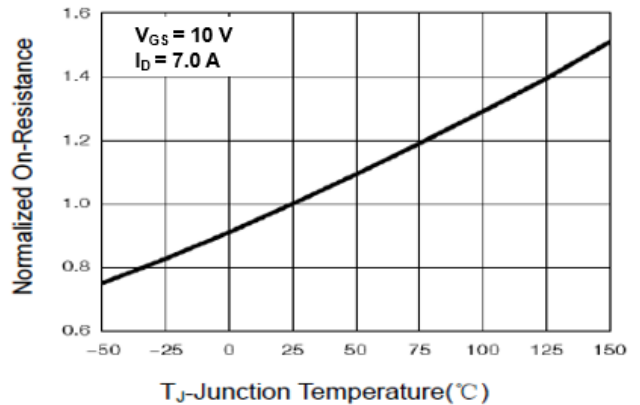


Figure6. Drain-Source on Resistance



YJL07P03AL

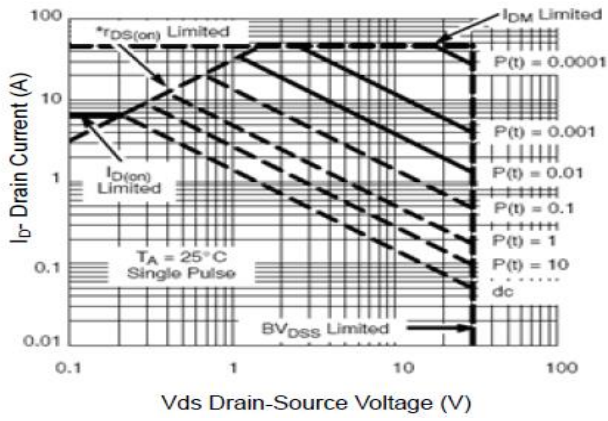


Figure7. Safe Operation Area

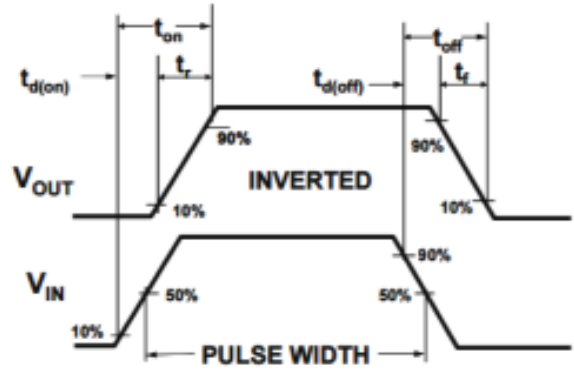
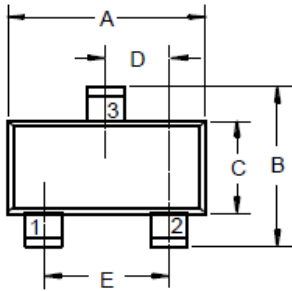


Figure8. Switching wave



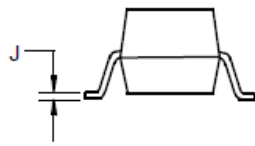
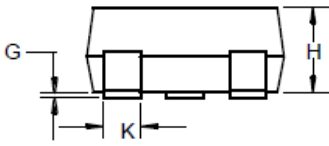
■ SOT-23-3L Package information

SOT-23-3L

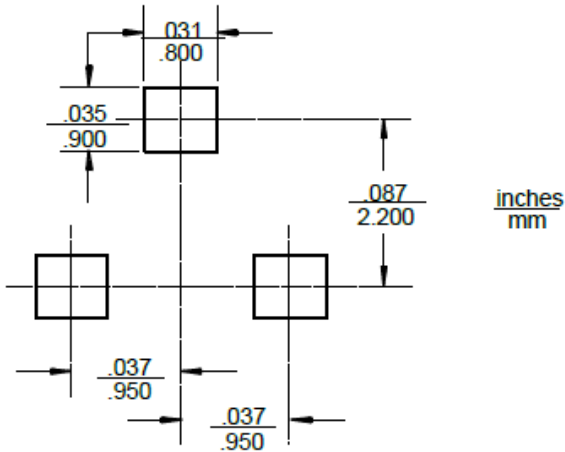


- 1. GATE
- 2. SOURCE
- 3. DRAIN

DIMENSIONS					
DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	.113	.117	2.87	2.97	
B	.108	.112	2.75	2.85	
C	.061	.065	1.55	1.65	
D	.036	.038	.914	.965	
E	.073	.077	1.85	1.95	
G	.0016	.0039	.04	.100	
H	.044	.049	1.12	1.25	
J	.006	.007	.14	.17	
K	.013	.015	.34	.37	



■ SOT-23-3L Suggested Pad Layout





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